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ZnO decorated Sn₃O₄ nanosheet nano-heterostructure: a stable photocatalyst for water splitting and dye degradation under natural sunlight

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Herein, a facile hydrothermally-assisted sonochemical approach for the synthesis of a ZnO decorated Sn₃O₄ nano-heterostructure is reported. The phase purity of the nano-heterostructure was confirmed by X-ray diffraction and Raman spectroscopy. The morphological analysis demonstrated a nanosheet-like structure of Sn₃O₄ with a thickness of 20 nm, decorated with ZnO. The optical band gap was found to be 2.60 eV for the ZnO@Sn₃O₄ nano-heterostructure. Photoluminescence studies revealed the suppression of electron-hole recombination in the ZnO@Sn₃O₄ nano-heterostructure. The potential efficiency of ZnO@Sn₃O₄ was further evaluated towards photocatalytic hydrogen production via H₂O splitting and degradation of methylene blue (MB) dye. Interestingly, it showed significantly superior photocatalytic activity compared to ZnO and Sn₃O₄. The complete degradation of MB dye solution was achieved within 40 min. The nano-heterostructure also exhibited enhanced photocatalytic activity towards hydrogen evolution (98.2 μmol h⁻¹/0.1 g) via water splitting under natural sunlight. The superior photocatalytic activity of ZnO@Sn₃O₄ was attributed to vacancy defects created due to its nano-heterostructure.

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1 Introduction

Recently, the discharge of industrial wastewater containing organic contaminants has led to serious environmental hazards. Commonly, biologically non-degradable waste water effluents contain synthetic pigments, organic dyes and phenolic contaminants, which cause a serious problem to aquatic life. Moreover, the higher stability of modern synthetic organic contaminants hampers orthodox biological treatments/methods and results in ineffectual degradation for the removal of these organic contaminants.^{1,2} Broadly, there are two approaches for the removal of toxic contaminants from waste water. (i) Contaminants are degraded and broken down into harmless moieties.³ (ii) Contaminants are removed via an adsorption technique.⁴ The first approach is more effective, in which reactive oxygen species are generated using a suitable semiconducting photocatalyst by advanced oxidation processes (AOP).⁵⁻⁷ TiO₂ and ZnO are the most commonly used semiconductor photocatalysts due to their high efficiency in the

degradation of organic pollutants under UV irradiation.⁸⁻¹⁰ However, these photocatalysts also possess some limitations, such as being excited only by ultraviolet light or the recombination rates of photogenerated holes and electrons being high, which consequently restrict their application due to their low utilization of solar energy.^{11,12} Therefore, several ideas have been put forward by researchers to promote the photocatalytic activity by the effective utilization of solar light energy. These efforts include increasing the hole concentration through doping, varying the particle size to enhance the surface area, mixing the semiconductor catalyst with suitable metal/metal oxide nanomaterials and the development of new photocatalysts with a narrow band gap.¹³⁻¹⁷ Among these techniques, the fabrication of composite materials based on two different metal oxides with variable band gap energies provides an effective way to tackle the above-mentioned issues.¹⁸⁻²² In this regard, there are various reports available on different coupled metal oxides, such as SnO₂-ZnO, TiO₂-WO₃, CZTS-TiO₂, Bi₂O₃/Bi₅O₇NO₃, ZnO-SnO₂ and TiO₂-SnO₂.²³⁻²⁸

Recently, heterovalent tin oxide (Sn₃O₄) with various nano-morphs, including nanosheets, nanoflowers, nanobelts, nanolayers, etc., has been used as a potential catalyst due to its narrow band gap and chemical stability.²⁹⁻³² The photocatalytic performance of pristine Sn₃O₄ is believed to be due to the variable oxidation state of Sn: *i.e.* Sn²⁺ and Sn⁴⁺.³² Reports in the

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desorption equilibrium of the MB dye with the photocatalysts. After 1 h, the mixture was exposed to sunlight for photo-degradation. At regulated intervals of time, 5 mL of reaction mixture was collected, centrifuged to remove the catalyst and then analysed using a UV-visible spectrometer. The progress of the reaction was monitored by observing changes in the intensity of the maximum absorption of the MB dye at 662 nm.

3 Results and discussion

The crystal structures and phase purity of as-synthesized ZnO, Sn₃O₄ and ZnO@Sn₃O₄ products were examined by powder XRD, as shown in Fig. 1. Curve (a), the X-ray diffractogram of pristine ZnO, shows diffraction peaks at 31.2°, 34.4°, 36.6°, 47.2°, 56.4°, 62.7°, 66.3°, 67.5° and 69.2° corresponding to the (100), (002), (101), (102), (110), (103), (200), (112) and (201) planes of the hexagonal wurtzite phase of ZnO (JCPDS card no. 89-0510).³² Curve (b), the X-ray diffractogram of as-synthesized Sn₃O₄, corresponds to the (101), (111), (122), (130), and (132) reflection planes, attributed to the triclinic phase (JCPDS card no. 16-0737).²³ The XRD pattern of the as-synthesized ZnO@Sn₃O₄ nano-heterostructure is depicted in Fig. 1(c). It can be seen that the XRD pattern exhibits diffraction peaks corresponding to both ZnO and Sn₃O₄, indicating the formation of a ZnO phase along with Sn₃O₄. No other impurity peaks were detected.

The XRD data were further utilized for determining the crystallite size using the Debye–Scherrer formula. The estimated crystallite sizes were found to be 48.6, 36.2 and 34.4 for pristine ZnO, Sn₃O₄ and ZnO@Sn₃O₄ nanostructures, respectively.

The as-synthesized ZnO, Sn₃O₄ and ZnO@Sn₃O₄ samples were further analyzed by Raman spectroscopy and the results are shown in Fig. 2. Curve (a) represents the Raman spectrum of pristine ZnO. From the spectrum, the vibrational peaks appearing at 332, 438 and 698 cm^{−1} for ZnO can be clearly seen. The most intense peak located at 438 cm^{−1} is characteristic of the E2 mode of the hexagonal wurtzite structure.³³

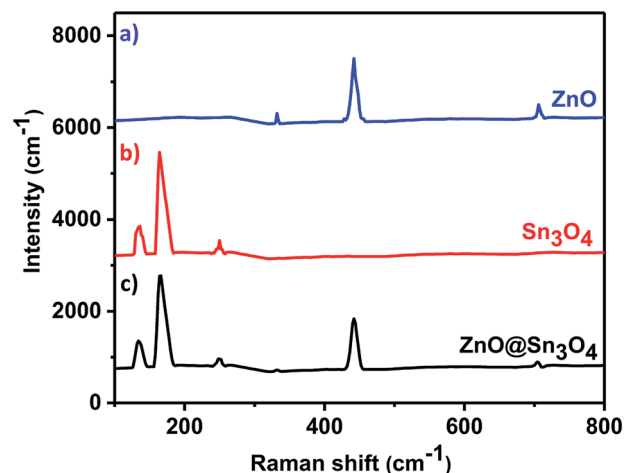


Fig. 2 Room temperature Raman spectra of (a) ZnO, (b) Sn₃O₄ and (c) ZnO@Sn₃O₄.

The other modes with frequencies of 332 and 698 cm^{−1} are due to multiphonon scattering processes and cannot be explained within the framework of bulk single phonon modes.³³ For pristine Sn₃O₄ (curve (b)), the two sharp peaks at 135 and 168 cm^{−1} are characteristic peaks of triclinic Sn₃O₄. However, the weak peak at 243 cm^{−1} may be due to the oxidation of the sample.³⁰ Curve (c) shows the Raman spectrum of ZnO@Sn₃O₄, which exhibits mixed peaks for Sn₃O₄ and ZnO. This confirms that all of the samples exhibit crystalline peaks and that these results are in good accordance with the XRD results.

Based on the above characterization features, a mechanism of the formation of ZnO@Sn₃O₄ has been proposed. Sn₃O₄ was well dispersed homogeneously in a 1 : 1 ethanol : water mixture. Zn²⁺ and OH[−] ions were provided by zinc acetate and sodium hydroxide, respectively, which reacted to form a stable Zn(OH)₄^{2−} complex. Under sonochemical treatment, the sonolysis of water generates various radicals, such as [•]H, [•]OH, [•]OH₂ and [•]O₂[−]. The [•]O₂[−] plays an important role in the formation of ZnO nanostructures. The formation reactions of ZnO are represented by eqn (1)–(3):³⁴

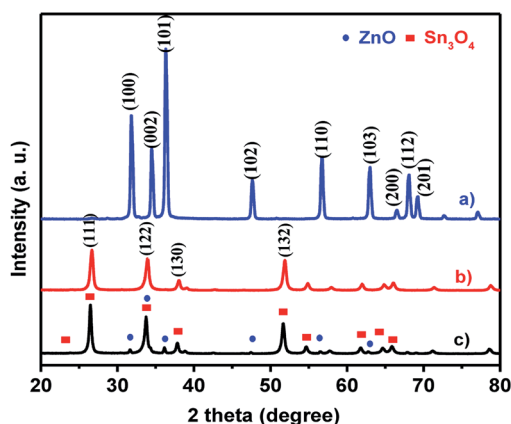
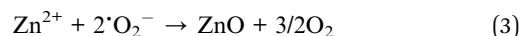
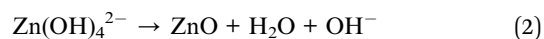


Fig. 1 X-ray diffraction patterns (XRD) of (a) ZnO, (b) Sn₃O₄ and (c) ZnO@Sn₃O₄.

The morphological analysis of ZnO, Sn₃O₄ and ZnO@Sn₃O₄ nano-heterostructures was further analyzed by FESEM and the results are depicted in Fig. 3. From Fig. 3(a) and (b), it can be seen that pristine ZnO exhibits a hexagonal rod-like morphology with a width ranging from 50–180 nm to 200–400 nm in length. The FESEM analysis of pristine Sn₃O₄, as depicted in Fig. 3(c) and (d), reveals that it consists of irregularly-shaped sheets with a thickness of about 20 nm, with some flat nanocrystals deposited on them. Fig. 3(e) and (f) show that in the FESEM analysis of as-synthesized ZnO@Sn₃O₄ nano-heterostructures, the morphology was retained. However, sheet-



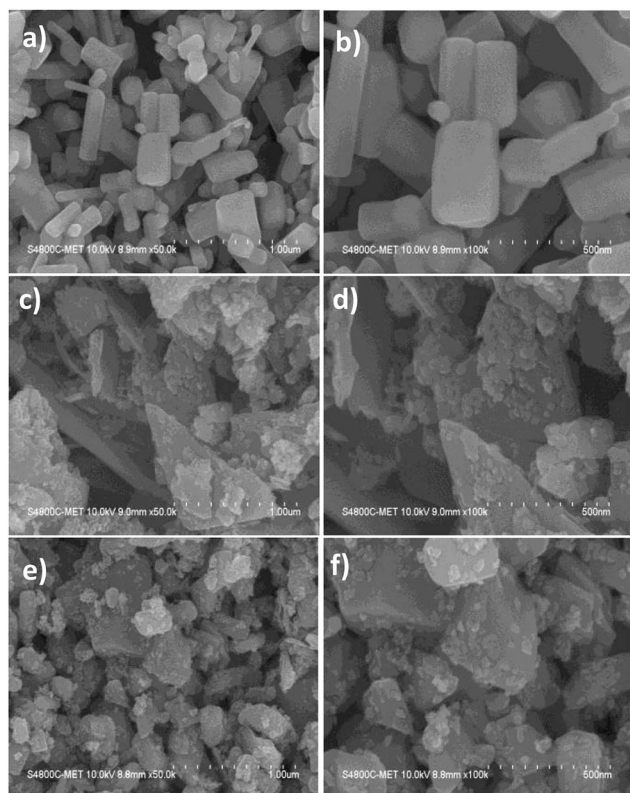


Fig. 3 FESEM images of (a and b) ZnO, (c and d) Sn_3O_4 , (e and f) $\text{ZnO@Sn}_3\text{O}_4$, respectively.

like nanostructures with deposited ZnO nanocrystals of reduced size were observed for these composites. The reduced size of the nanosheets and deposited nanocrystals might be attributed to ultrasound irradiation during the sonochemical synthesis.

The crystallinity and heterojunction of the as-synthesized samples were confirmed using field emission transmission electron microscopy (FETEM). Fig. 4 shows the FETEM images of $\text{ZnO@Sn}_3\text{O}_4$. Fig. 4(a) and (b) reveal a sheet-like morphology with the thickness of the nanosheet less than 30 nm and some nanocrystals of ZnO present on the Sn_3O_4 nanosheets. Fig. 4(c) represents the SAED pattern of the sample, which clearly shows the polycrystalline nature of $\text{ZnO@Sn}_3\text{O}_4$. Further, from the HRTEM image of the $\text{ZnO@Sn}_3\text{O}_4$ (Fig. 4(d)), the close connection/binding of ZnO and Sn_3O_4 can be clearly seen. The lattice fringes obtained from different regions with lattice spacings of 0.33 and 0.25 nm can be assigned to the (111) plane of triclinic Sn_3O_4 and the (002) plane of wurtzite ZnO, respectively.

Fig. 5 shows the elemental mapping of the $\text{ZnO@Sn}_3\text{O}_4$ nanostructures. From the figure, the signals pertaining to Zn, Sn and O have a uniform spatial distribution. For further confirmation of the uniform distribution of Zn, Sn and O in $\text{ZnO@Sn}_3\text{O}_4$ nanosheets, spot EDS analysis was carried out and the results are shown in Fig. 5(b)–(f). In the figures, no peaks corresponding to any impurities can be observed and the stoichiometric ratios used for Zn and Sn were found to be in good agreement with those used in the synthetic architecture during the synthesis.

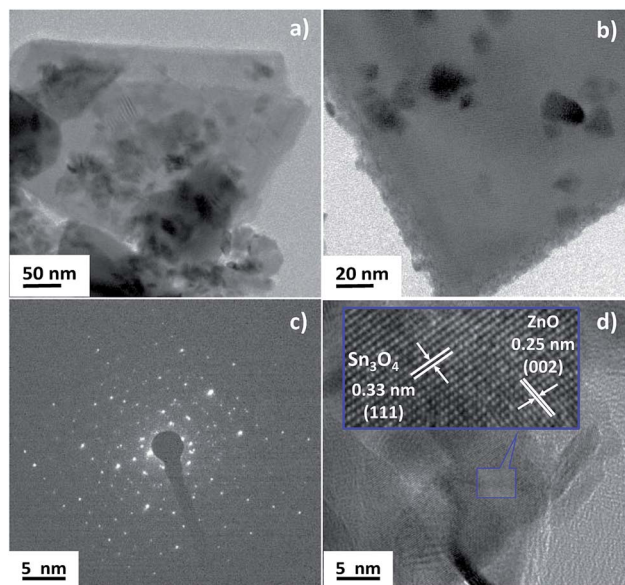


Fig. 4 TEM (a and b), SAED pattern (c), HRTEM (d) images of $\text{ZnO@Sn}_3\text{O}_4$, respectively.

From Fig. 6, it can be seen that pristine ZnO (curve (a)) and Sn_3O_4 (curve (b)) exhibit absorption onsets at 391 nm and 445 nm, respectively. Whereas $\text{ZnO@Sn}_3\text{O}_4$ (curve (c)) exhibits absorption onsets at 392 nm and 460 nm. These can be attributed to the presence of both Sn_3O_4 and ZnO in the nanostructures.³⁵ This data was further utilized for the determination of band gaps of the as-synthesized materials. The corresponding Tauc plot is shown in the inset of Fig. 6. From the figure the estimated band gap energies of ZnO, Sn_3O_4 and $\text{ZnO@Sn}_3\text{O}_4$ were found to be 3.36 eV, 2.77 eV and 2.60 eV, respectively. These results further demonstrated that the band gap of pristine Sn_3O_4 can be fine-tuned simply by coupling with ZnO.

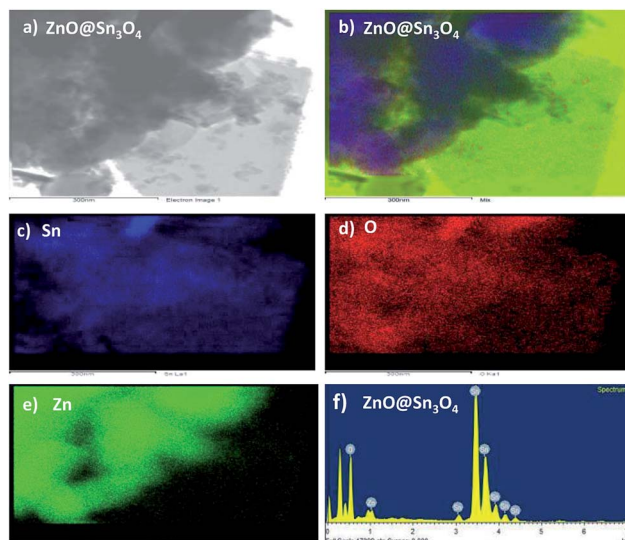


Fig. 5 (a) TEM image of $\text{ZnO@Sn}_3\text{O}_4$ for EDS; (b–f) EDS element mapping data of Zn, Sn and O elements for $\text{ZnO@Sn}_3\text{O}_4$, respectively.



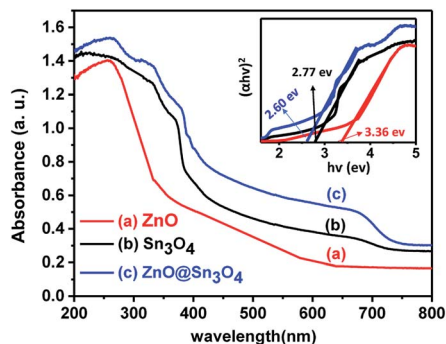


Fig. 6 UV-vis absorption spectra of (a) ZnO, (b) Sn_3O_4 and (c) $\text{ZnO@Sn}_3\text{O}_4$. The inset shows $(\alpha h\nu)^2$ vs. photon energy ($h\nu$) spectra for the calculation of optical band gap by extrapolation on the $h\nu$ axis at $\alpha = 0$.

The PL spectra of the as-synthesized ZnO, Sn_3O_4 and $\text{ZnO@Sn}_3\text{O}_4$ samples were performed to understand the rate of photogenerated electrons and holes (Fig. 7). In general, a higher PL emission peak intensity arises due to higher recombination of photogenerated electron-hole pairs, whereas weak emission intensities indicate lower recombination rates and consequently the extended participation of photoexcited charge carriers in the photoreaction.³⁶ In the PL spectrum of pristine ZnO, the weak emission peak at 398 nm is due to UV and the sharp emission peak at 498 nm corresponds to green emission.³⁷ Pristine Sn_3O_4 exhibits a sharp emission peak at 510 nm, which can be attributed to the intrinsic luminescence of Sn_3O_4 .³⁰ The PL spectrum of $\text{ZnO@Sn}_3\text{O}_4$ also exhibits an emission peak at 510 nm. However, the PL peak intensity is considerably lowered. The significant decrease in the PL peak intensities of $\text{ZnO@Sn}_3\text{O}_4$ nanostructures clearly indicate the efficient inhibition of photoexcited electron-hole recombination.³⁸

The particle size distribution results of as-synthesized ZnO, Sn_3O_4 and $\text{ZnO@Sn}_3\text{O}_4$ are shown in Fig. 8. From the figure, it can be seen that $\text{ZnO@Sn}_3\text{O}_4$ exhibits a lesser particle size compared to the pristine ZnO and Sn_3O_4 samples. The calculated mean Gaussian diameters observed for the ZnO, Sn_3O_4

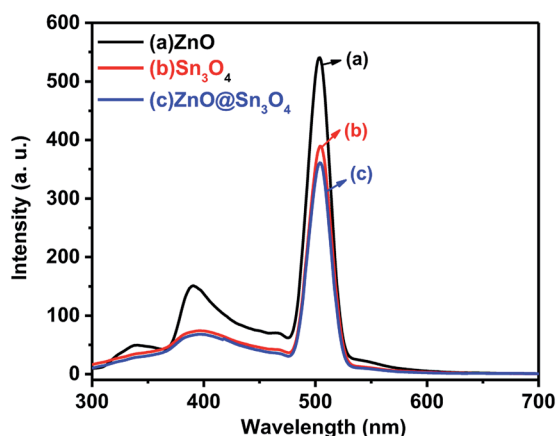


Fig. 7 PL spectra of (a) ZnO, (b) Sn_3O_4 and (c) $\text{ZnO@Sn}_3\text{O}_4$.

and $\text{ZnO@Sn}_3\text{O}_4$ samples were 418.2, 319.2 and 290 nm, respectively. These results are in good agreement with the obtained FESEM results.

Photocatalytic activity

Here in the present study, the photocatalytic activities of as-synthesized ZnO, Sn_3O_4 and $\text{ZnO@Sn}_3\text{O}_4$ nanostructures were evaluated by the photodegradation of methylene blue as a representative organic dye. Additionally, a direct comparison of the as-prepared samples with Degussa-P25 was also carried out. MB ($\text{C}_{16}\text{H}_{18}\text{ClN}_3\text{S}$) is a well-known organic dyestuff and it is often used to a large extent for various purposes.

During the photodegradation experiments, 50 mg of photocatalyst was dispersed in 100 mL of 10 ppm MB aqueous solution and stirred in the dark to achieve adsorption-desorption equilibrium. After 1 h the MB dye solution containing the catalyst was exposed to sunlight. The progress of the photodegradation process was monitored using the change in intensities of the characteristic absorption of MB dye at 662 nm.

The experimental results pertaining to MB dye adsorbed and degraded at different time intervals under different experimental conditions are depicted in Fig. 9(a). For comparison, a blank experiment without any catalyst was also performed. In the absence of catalyst, MB dye was hardly degraded, but degradation of MB dye was achieved in the presence of a catalyst under sunlight irradiation.

From Fig. 9(a) it can be seen that approximately 90% degradation of MB dye can be achieved in the presence of Sn_3O_4 and ZnO within 60 and 70 minutes, respectively, whereas P25 was able to degrade the same amount of MB dye within 65 min. However, the photodegradation efficiency is significantly enhanced in the presence of $\text{ZnO@Sn}_3\text{O}_4$ nanostructures. The spectral changes during the photodegradation of MB dye in the presence of $\text{ZnO@Sn}_3\text{O}_4$ under sunlight illumination are shown in Fig. 9(b). It can be clearly seen from the figure that more than 50% of the MB dye was degraded within the initial 20 min and complete degradation was achieved within a mere 40 min. This enhanced photoactivity of $\text{ZnO@Sn}_3\text{O}_4$ nano-heterostructures can be attributed to the narrow band gap and decreased e^-

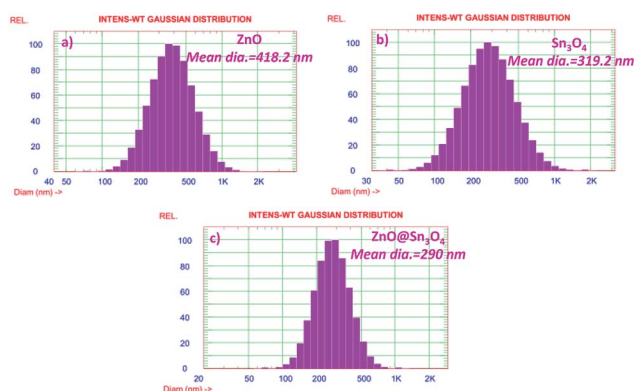


Fig. 8 Particle size distribution histogram of (a) ZnO, (b) Sn_3O_4 and (c) $\text{ZnO@Sn}_3\text{O}_4$, respectively.



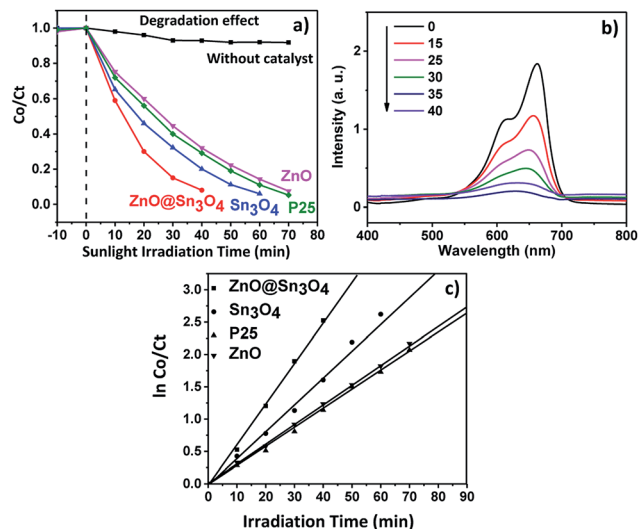


Fig. 9 (a) Plot of change in absorbance vs. irradiation time in the presence of ZnO, Sn_3O_4 , P25 and $\text{ZnO@Sn}_3\text{O}_4$; (b) spectral changes of degradation of MB dye in the presence of $\text{ZnO@Sn}_3\text{O}_4$; (c) pseudo-first-order kinetic plots of $\ln(C_0/C_t)$ vs. irradiation time for the degradation of methylene blue (MB) using ZnO, Sn_3O_4 , P25 and $\text{ZnO@Sn}_3\text{O}_4$.

and h^+ recombination achieved due to the coupling of ZnO and Sn_3O_4 .

Further, the experimental data was utilized for studying the photodegradation kinetics. The corresponding plots of $\ln C_0/C_t$ vs. irradiation time are depicted in Fig. 9(c). The rate constants for the ZnO, P25, Sn_3O_4 and $\text{ZnO@Sn}_3\text{O}_4$ samples were found to be 0.0128, 0.0131, 0.0149 and 0.0178 min^{-1} , respectively. Thus, the maximum photodegradation rates (*i.e.* 0.0178 min^{-1} with excellent linear correlation (Table 1)) were demonstrated by the $\text{ZnO@Sn}_3\text{O}_4$ photocatalyst, suggesting pseudo first-order kinetics.

Considering the narrow band gap of as-synthesized $\text{ZnO@Sn}_3\text{O}_4$, these samples were also studied for photocatalytic hydrogen production *via* H_2O splitting. Fig. 10 depicts a plot of hydrogen production from water with respect to time using the ZnO, Sn_3O_4 and $\text{ZnO@Sn}_3\text{O}_4$ nano-heterostructures both in the dark and under solar light. The maximum hydrogen evolution (98.2 $\mu\text{mol h}^{-1}/0.1 \text{ g}$) was obtained using the $\text{ZnO@Sn}_3\text{O}_4$ nanoparticles, and it was considerably higher than in previous reports.^{28,38} The results demonstrate that the $\text{ZnO@Sn}_3\text{O}_4$ nano-heterostructures could split water under sunlight conditions. These excellent characteristics of $\text{ZnO@Sn}_3\text{O}_4$ can be ascribed to the strong absorption of solar

Table 1 Summary of the pseudo-first-order kinetics for the photocatalytic degradation of methylene blue (MB) using ZnO, Sn_3O_4 , P25 and $\text{ZnO@Sn}_3\text{O}_4$

Catalyst	R^2	k (min^{-1})
ZnO	0.973	0.0128
P25 (TiO_2)	0.974	0.0131
Sn_3O_4	0.986	0.0149
$\text{ZnO@Sn}_3\text{O}_4$	0.998	0.0178

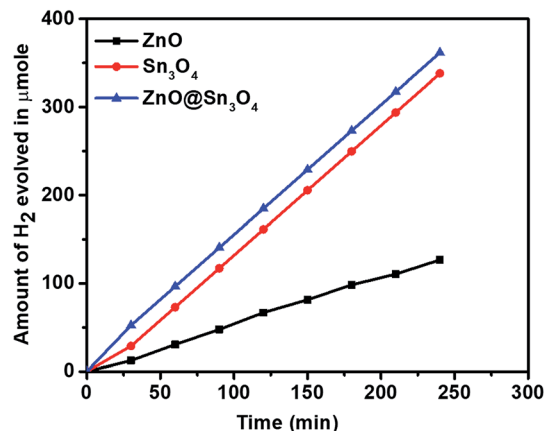


Fig. 10 Hydrogen production as a function of irradiation time in the presence of ZnO, Sn_3O_4 and $\text{ZnO@Sn}_3\text{O}_4$.

light due to the narrow band gap, which facilitates electron-hole pair formation and their transportation to the surface of the catalyst where adsorbed H_2O can be split into H_2 and O_2 .

A possible mechanism for the degradation of methylene blue and hydrogen production by ZnO decorated Sn_3O_4 nano-heterostructures can be elucidated with the help of two probable schemes, as illustrated in Fig. 11. The band alignment in ZnO and Sn_3O_4 is suitable for a 'type II' heterostructure system.^{31,39,43} In the first probable mechanism, as shown in Fig. 11(a), in step (i), upon sunlight irradiation, photoexcitation of ZnO and Sn_3O_4 can take place, forming e^-/h^+ pairs. The electrons in the VB of both ZnO and Sn_3O_4 migrate to their respective CBs. In step (ii), as the CB of Sn_3O_4 is situated at a more negative energy potential (−0.58 eV) than the CB of ZnO (−0.39 eV), the photoinduced electrons migrate from the CB of Sn_3O_4 to the CB of ZnO. Whereas the VB of ZnO is situated at a more positive energy potential (+2.97 eV) than the VB of Sn_3O_4 (+2.74 eV), so the holes migrate from the VB of ZnO to the VB of Sn_3O_4 . As a result, the photoinduced electrons accumulating in the CB of ZnO and the holes in the VB of Sn_3O_4 are well separated from each other. The potential energy value for the oxygen reduction reaction is −0.17 eV.

In the second probable mechanism, the Z-scheme heterostructure^{40,41} can give a good interpretation of all the experimental results (Fig. 11(b)). For ZnO, the photoinduced e^-/h^+ in

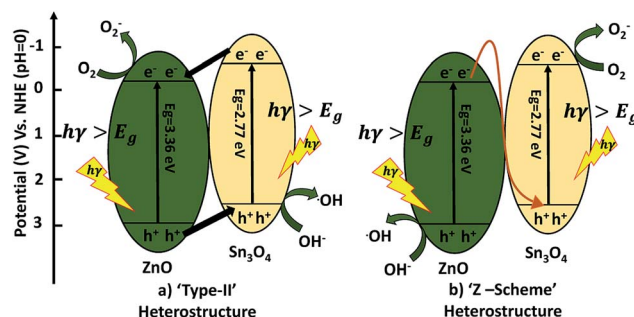
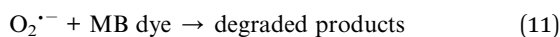
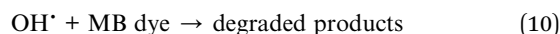
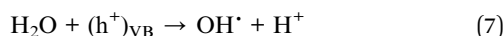
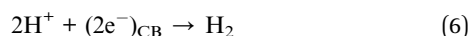
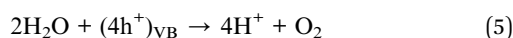
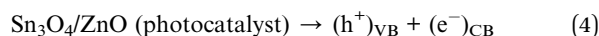


Fig. 11 Schematic diagram of electron transfer in the $\text{ZnO@Sn}_3\text{O}_4$.



ZnO tend to recombine and few of them take part in the photocatalytic reaction, resulting in a relatively low activity. For the ZnO decorated Sn_3O_4 nano-heterostructures Sn_3O_4 can significantly prolong the light utilization from UV to visible light. Under sunlight irradiation, the photoinduced h^+ are retained in the VB of ZnO, but the e^- migrate from the CB of ZnO to the VB of Sn_3O_4 . This mechanism can maintain at least a half of the photoinduced e^-/h^+ separated on opposite sides of the nano-heterostructure. Then, the e^- originating in the CB of Sn_3O_4 (-0.58 eV) can easily reduce O_2 to $\text{O}_2^{\cdot-}$ since their potential is more negative than that of ZnO. Meanwhile, the h^+ in the VB of ZnO ($+2.97$ eV) have a higher ability to oxidize OH^- into $\cdot\text{OH}$ radicals. These photogenerated radicals can then bring about the degradation of MB dye molecules or H_2O splitting. The overall mechanism is represented by following reactions.^{42,43}



The higher activity of the nano-heterostructures is also evidenced by the decline in the PL peak intensity. This shows the inhibition of electron-hole recombination, which was responsible for enhanced photocatalytic activity. The synthesized ZnO, Sn_3O_4 and $\text{ZnO@Sn}_3\text{O}_4$ could not split water under dark conditions, either. However, under sunlight light irradiation a significant amount of H_2 was produced from water splitting by the synthesized Sn_3O_4 and $\text{ZnO@Sn}_3\text{O}_4$. Further, the stability of $\text{ZnO@Sn}_3\text{O}_4$ was tested by repeating the experiments using the same $\text{ZnO@Sn}_3\text{O}_4$ photocatalyst after recycling (Fig. 12). In

a nutshell, the $\text{ZnO@Sn}_3\text{O}_4$ nano-heterostructures were observed to be good stable photocatalysts under natural sunlight.

4 Conclusions

A novel, highly efficient $\text{ZnO@Sn}_3\text{O}_4$ nano-heterostructure photocatalyst obtained by a facile hydrothermal assisted sonochemical method has been demonstrated. Considering that the absorption edge of $\text{ZnO@Sn}_3\text{O}_4$ is well within the visible region, the photocatalytic degradation of methylene blue (MB) and hydrogen production from H_2O under sunlight were performed. The prepared $\text{ZnO@Sn}_3\text{O}_4$ sample showed excellent photocatalytic activity for methylene blue degradation and for hydrogen production ($98.2 \mu\text{mole h}^{-1}/0.1 \text{ g}$) under natural sunlight. A suitable mechanism of the photocatalytic process was proposed. This study opens up a new possibility in the investigation of $\text{ZnO@Sn}_3\text{O}_4$ nanostructures and promotes their practical applications in environmental issues.

Conflicts of interest

There are no conflicts of interest to declare.

Acknowledgements

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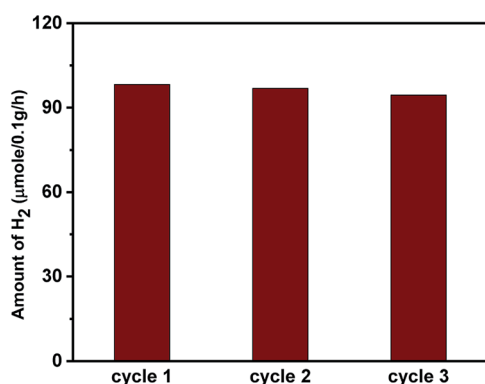
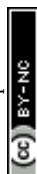


Fig. 12 Photocatalytic H_2 evolution cycle of $\text{ZnO@Sn}_3\text{O}_4$ nanostructures under sunlight irradiation.



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